

TC74VHCU04F, TC74VHCU04FN, TC74VHCU04FT

Hex Inverter

The TC74VHCU04 is an advanced high speed CMOS INVERTER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

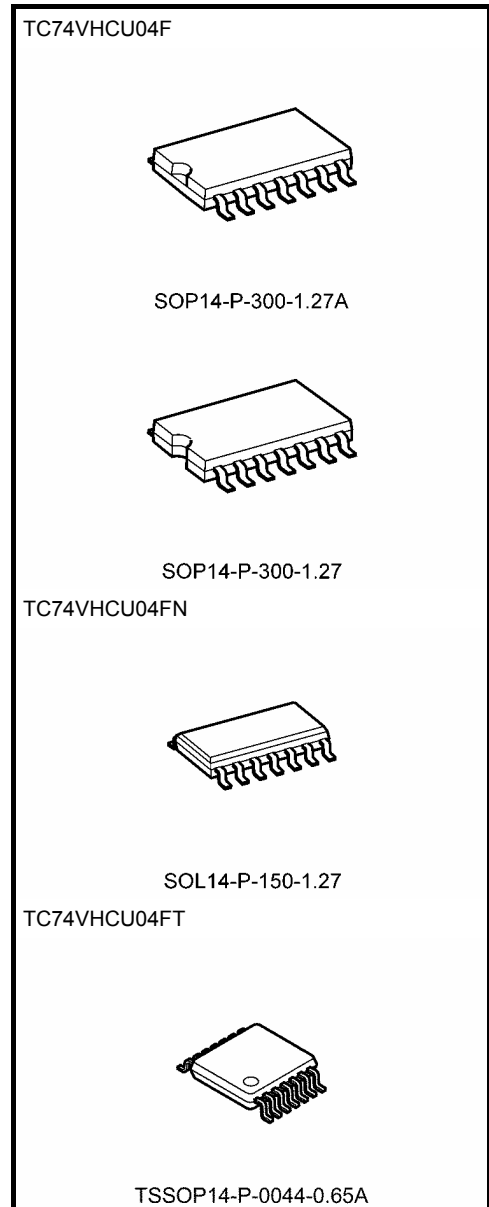
Since the internal circuit is composed of a single stage inverter, it can be used in analog applications such as crystal oscillators.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

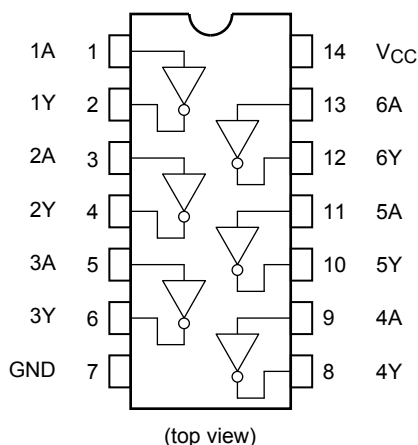
- High speed: $t_{pd} = 3.5 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 2 \text{ }\mu\text{A (max)}$ at $T_a = 25^\circ\text{C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 10\% V_{CC}$ (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC} \text{ (opr)} = 2 \text{ V to } 5.5 \text{ V}$
- Low noise: $V_{OLP} = 0.8 \text{ V (max)}$
- Pin and function compatible with 74ALS04

Note: xxxFN (JEDEC SOP) is not available in Japan.

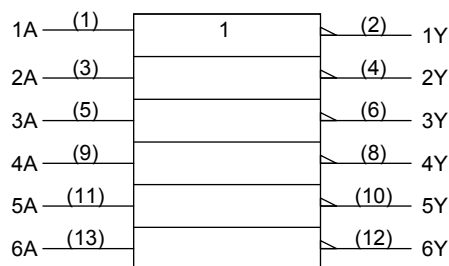


Weight	
SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)

Pin Assignment



IEC Logic Symbol



Truth Table

A	Y
L	H
H	L

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to 7.0	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65 to 150	$^{\circ}C$

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	$^{\circ}C$

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V _{CC} (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V _{IH}	V _{OUT} = V _{OL}		2.0	1.70	—	—	1.70	—	V
				3.0 to 5.5	V _{CC} × 0.8	—	—	V _{CC} × 0.8	—	
Low-level input voltage	V _{IL}	V _{OUT} = V _{OH}		2.0	—	—	0.30	—	0.30	V
				3.0 to 5.5	—	—	V _{CC} × 0.2	—	V _{CC} × 0.2	
High-level output voltage	V _{OH}	V _{IN} = V _{IL}	I _{OH} = -50 μA	2.0	1.8	2.0	—	1.8	—	V
				3.0	2.7	3.0	—	2.7	—	
		V _{IN} = GND	I _{OH} = -4 mA	3.0	2.58	—	—	2.48	—	
				4.5	3.94	—	—	3.80	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	2.0	—	0.0	0.2	—	0.2	V
				3.0	—	0.0	0.3	—	0.3	
		V _{IN} = V _{CC}	I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
				4.5	—	—	0.36	—	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
				5.5	—	—	2.0	—	20.0	
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	2.0	—	20.0	μA

AC Characteristics (input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V _{CC} (V)	C _L (pF)	Min	Typ.	Max		Min
Propagation delay time	t _{pLH}	—	3.3 ± 0.3	15	—	5.0	8.9	1.0	10.5	ns
				50	—	7.5	11.4	1.0	13.0	
	t _{pHL}	—	5.0 ± 0.5	15	—	3.5	5.5	1.0	6.5	
				50	—	5.0	7.0	1.0	8.0	
Input capacitance	C _{IN}	—		—	4	10	—	10	pF	
Power dissipation capacitance	C _{PD}	(Note)		—	9	—	—	—	pF	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

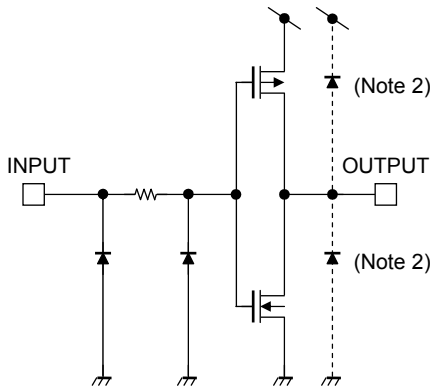
Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per gate)}$$

Noise Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C		Unit
			V _{CC} (V)	Typ. / Max	
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.5 / 0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.5 / -0.8	V
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	— / 4.0	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	— / 1.0	V

Input Equivalent Circuit

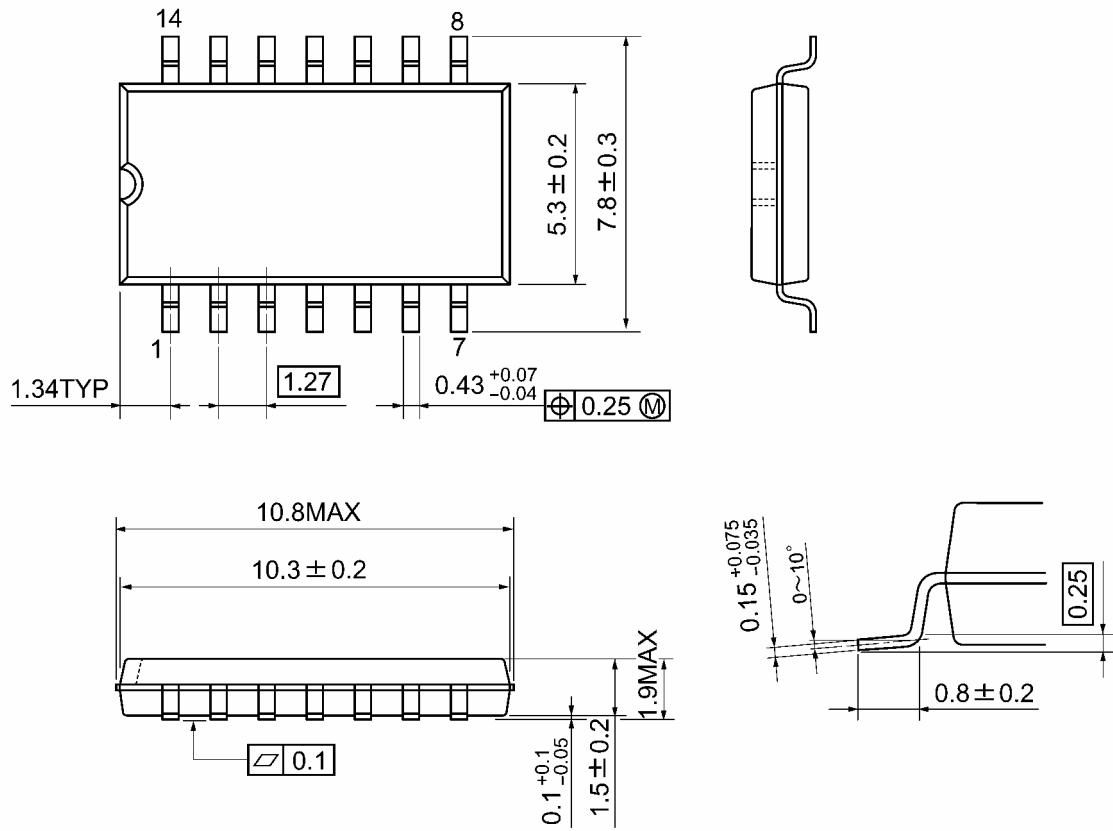


Note 2: Parasitic diode

Package Dimensions

SOP14-P-300-1.27A

Unit: mm

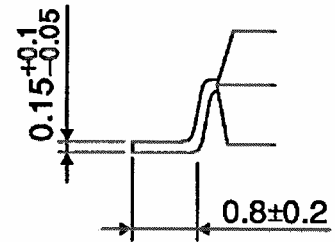
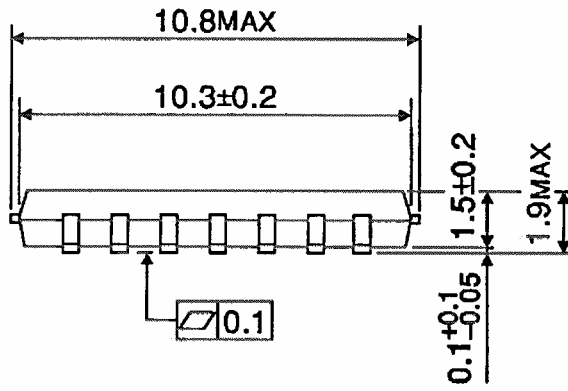
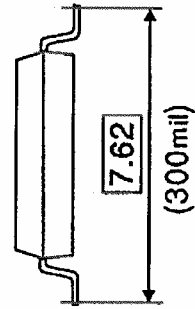
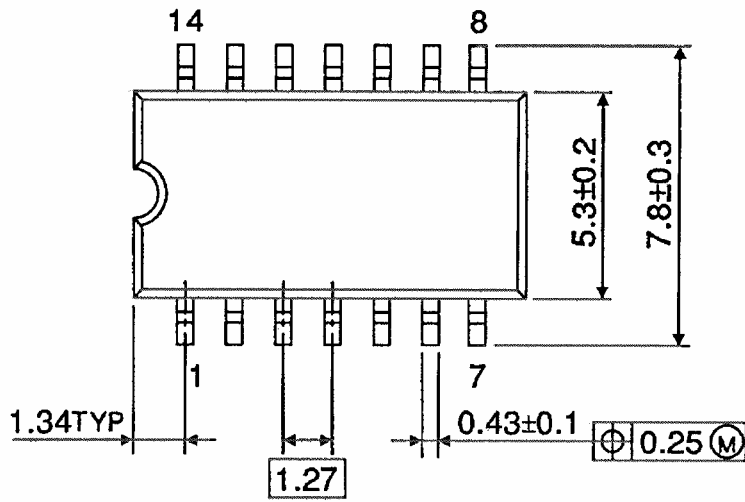


Weight: 0.18 g (typ.)

Package Dimensions

SOP14-P-300-1.27

Unit : mm

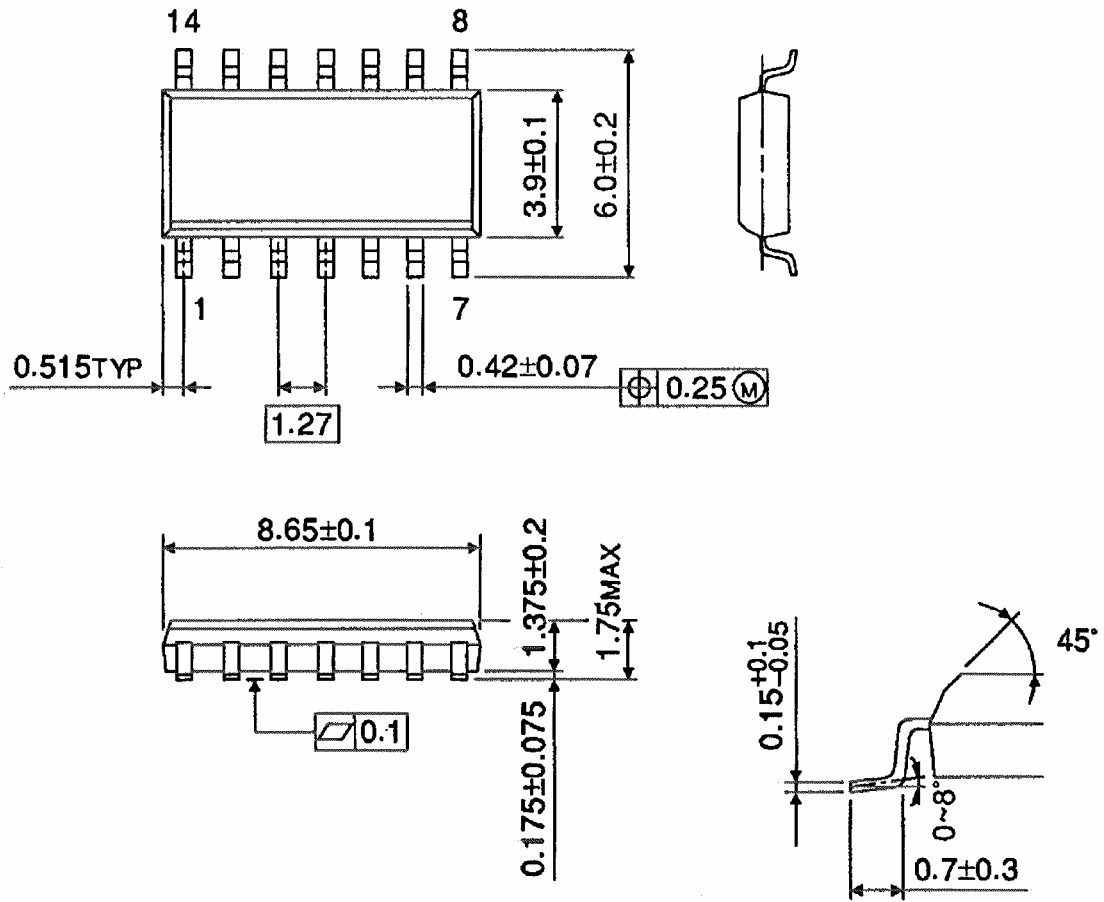


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27

Unit : mm



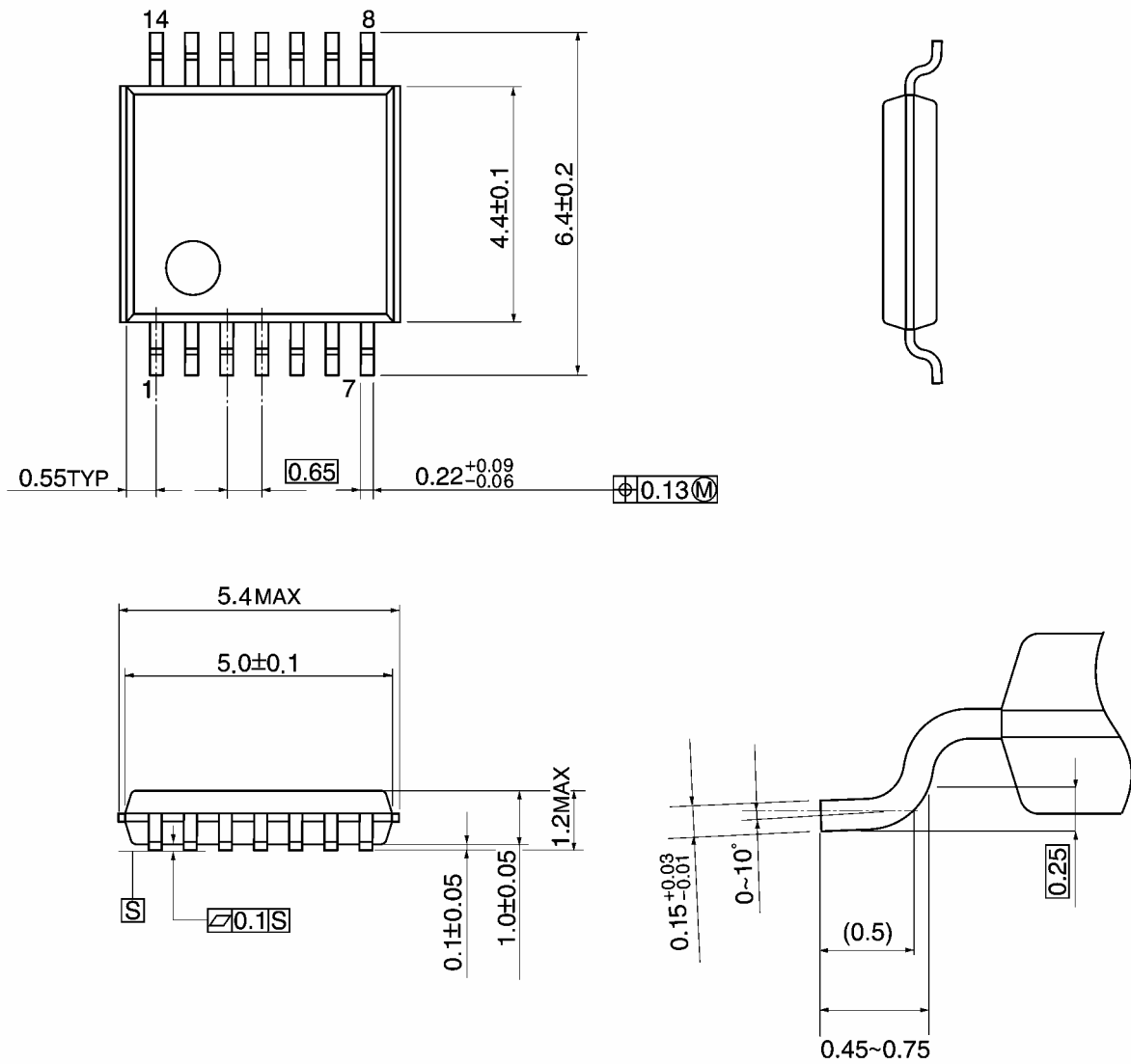
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages**SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A****RESTRICTIONS ON PRODUCT USE**

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